NSN 5961-00-849-5767

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View Online at https://aerobasegroup.com/nsn/5961-00-849-5767 **Inclosure Material:** Metal **Overall Length:** 0.560 inches **Overall Diameter:** 1.280 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No